TECHNICAL DATA DATASHEET 4724, REV. C

HERMETIC POWER SCHOTTKY RECTIFIER

DESCRIPTION: A 60-VOLT, 35 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_c = 25 °C UNLESS OTHERWISE SPECIFIED.

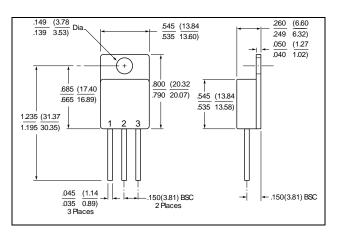
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	60	Volts
MAXIMUM DC OUTPUT CURRENT (@ $T_c=100$ °C) (Single, Doubler)	Ι _ο	30	Amps
MAXIMUM DC OUTPUT CURRENT (@ T _c =100 ^O C) (Common Cathode, Common Anode)	Ι _Ο	35	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)	I _{FSM}	570	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	1600	pF
MAXIMUM THERMAL RESISTANCE (Per leg)		1.5	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE		-55 to + 175	°C
MAXIMUM STORAGE TEMPERATURE RANGE		-55 to + 175	°C

ELECTRICAL CHARACTERISTICS

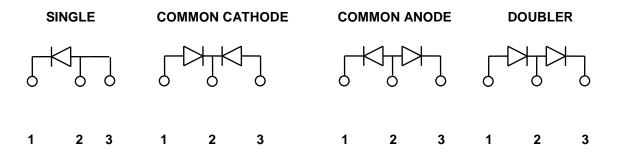
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed $(I_f = 30 \text{ Amps})$			
T _J =25 °C	V _f	0.83	Volts
T _J = 125 °C		0.78	
MAXIMUM REVERSE CURRENT (I _r @ 60 V PIV)			
T _J = 25 °C	l _r	4	mA
T _J = 125 °C		280	

TO-254

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Mechanical Dimensions: In inches / mm

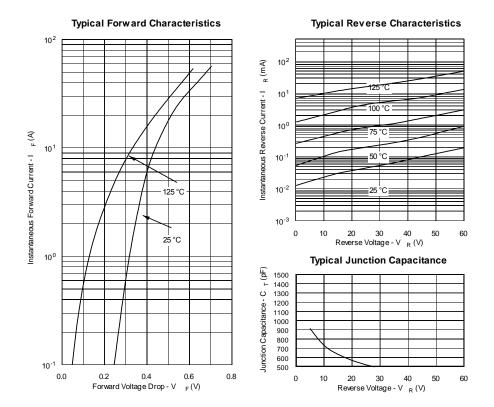


PINOUT TABLE			
ТҮРЕ	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	CATHODE/ ANODE	CATHODE

SHD125413 SHD125413D SHD125413N SHD125413P

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Curves shown are for bare die only.



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